VR-002
Vintage Radio Application Note

RECONDITIONING AND MODERNIZING
THE HEATHKIT HP-13 DC POWER SUPPLY

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SECTION I - INTRODUCTION, OVERVIEW, & HONORARIUM

This paper is a vintage radio technical document that describes the reconditioning, modification, and modernization of a Heathkit HP-13 DC power supply. This unit was designed by Heathkit back in the 1960s to provide the necessary supply voltages for mobile +12 VDC operation of Heathkit SB- and HW-series HF amateur transceivers and other equipment.

I procured this unit on Ebay and found it to be in fair condition. Although the unit was functional and structurally sound, it required significant reconditioning, modification, and modernization to restore it to “like-new” operational condition. This paper describes this process in detail along with the necessary supporting technical background.

Although this project did not pose any major technical challenges and was not particularly difficult, it is my hope that the enhanced technical detail provided will be helpful to other vintage radio afficionados interested in refurbishing the HP-13 and other power supplies with similar issues.

Also, visit my N6DC vintage radio website at www.rdfproducts.com/N6DC.Vintage.Radio.htm for possible revisions to this paper as well as other vintage radio technical articles.

** DANGER **

_The Heathkit HP-13 DC power supply contains dangerous high voltages that can be lethal if contacted._ Those intending to work on this power supply should be well-versed in working on equipment with high voltages present and be completely familiar with all necessary safety precautions. Those unfamiliar with these safety precautions or inexperienced in working on equipment containing high voltages should not open the unit.

HONORARIUM

This paper is written in honor of CWO James D. Henson (U.S. Army, retired) who served this country over a period of 30 years (1941-1971) that included three wars. CWO Henson built this HP-13 power supply in 1964 and had it in his possession until 2011. CWO Henson is still an active amateur radio operator operating as W5BVN out of Killeen, Texas.
SECTION II - SUMMARY CIRCUIT DESCRIPTION

Referring to the schematic of Figure 1, the HP-13 essentially is a transistorized inverter power supply that accepts +12 VDC (typically from an automotive electrical system), steps up the resulting AC voltage via a multi-secondary power transformer, and then rectifies and filters the various secondary voltages to obtain the desired DC outputs. The rated input voltage range is +12.0 to +14.5 VDC (negative ground). The rated maximum input current is 25 amperes at full load.

The HP-13 supplies three separate unregulated DC voltage outputs (in addition to a pass-thru +12 VDC filament voltage output). These DC output voltages are as follows:

**High Voltage** - The high voltage output is generated by a full-wave voltage doubler. Its rated output is +800 VDC no-load and +750 VDC @250 mA.

**Low Voltage** - The low voltage output is generated by a full-wave voltage doubler. Its rated output is +310 VDC no-load and +300 VDC @150 mA. This low voltage output can be reduced (for appropriate applications) by selecting the lower voltage tap on the T1 power transformer secondary. With the lower voltage tap selected, the rated output is +265 VDC no-load and +250 VDC @150 mA.

**Bias Voltage** - An adjustable bias voltage output is generated by a half-wave rectifier. This is a negative voltage rated at -40 to -130 VDC no-load, depending upon the setting of R10 (Bias Adj.). Current capacity is 20 mA at -130 VDC and 1 mA at -40 VDC.

Capacitive input filters are used for all three DC voltages. The low-voltage supply also employs an additional series filter choke (L1) followed by an additional shunt filter capacitor for improved AC ripple reduction.

The inverter switching frequency is nominally 1,500 Hz with loud audible ringing. Unlike modern inverters that employ switching frequencies above 20,000 Hz (and are inaudible as a result), inverters built back in the 1960s had to be designed using earlier generation power transistors that did not offer the enhanced high frequency performance available from modern power transistors. As a result, these inverters had to use much lower switching frequencies to operate efficiently.
Figure 1 - Heathkit HP-13 DC Power Supply Schematic
SECTION III - CLEANING & COSMETICS

As stated above, the HP-13 I procured on Ebay was functional and structurally sound, but somewhat shop-worn and aged. Even so, there was little repair work that needed to be done aside from replacing missing hardware, retightening some nuts, and conducting a general clean-up. Since the power output cable was found to be functional and in good condition, it was left as is.

Fortunately, this unit was assembled very well and required no rework to correct for assembly errors. In general however, workmanship for Heathkits must be checked carefully given that the assembly skill of the builder can vary over a wide range. In addition to inspecting solder joints, all Heathkits should be inspected for solder balls, solder splashes, and any other debris that may be lodged in the chassis. Of course, all foreign objects should be removed as part of the cleaning process. Upon completion of the reconditioning, I used cable ties to secure various wires and non-corrosive silicone RTV to secure various components.

The HP-13 includes a power relay that is used to switch the +12 VDC input power on or off. It was necessary to clean both sets of relay contacts (these are wired in parallel as per the schematic of Figure 1) since they were very dirty. I did this by cutting up a 3” x 5” index card into narrow strips and then soaking the end of one of these strips with spray contact cleaner. I then ran this soaked strip through the relay contact (manually pushing the relay contacts to their closed position to generate the friction necessary to clean the contacts as the strips were pulled through). I then repeated this process with a new strip until the strip pulled through the contacts clean.

Although the unit looked its age, no cosmetic restoration effort was made aside from general cleaning. Since my intent was to install this unit out-of-view from the operating console, I saw no reason to invest any effort into cosmetic restoration.
SECTION IV - SILICON RECTIFIER DIODE REPLACEMENT

A. DIODE REPLACEMENT

The HP-13 rectifiers (D1-D7 from Figure 1) are all 1960s-vintage 1N2071 silicon diodes. These diodes are rated at 600 PIV (peak inverse voltage) with a maximum average forward current rating of 750 mA. Although these are old diodes, they are fully adequate for this application. Even so, being 40+ years old and with newer and better diodes available at very low cost, it seemed prudent to replace them.

Although there are many modern silicon rectifier diodes available to replace the 1N2071, the 1N4007 is a particularly good choice in that it is widely used, readily available, and very inexpensive. Rated at 1,000 PIV with a maximum average forward current rating of 1.0 A, the 1N4007 is superior to the 1N2071 in all respects. Being very similar in size to the 1N2071, the 1N4007 is thus an excellent choice for a fit/form/function replacement for the 1N2071. The 1N4007 can be purchased in small quantities from Digi-Key Corp., Jameco Electronics, and Mouser Electronics. I purchased mine from Digi-Key Corp. (P/N 1N4007FSCT-ND) along with replacement electrolytic capacitors as discussed in Section V.

B. PLACING DIODES IN SERIES

As per the schematic of Figure 1, the full-wave voltage doubler employs series diode strings (D1/D2 and D3/D4) in each leg to increase the PIV ratings. To put some numbers on this, the required rectifier PIV rating for a full-wave voltage doubler is given by the following equation:

\[ \text{PIV} = 2.82 \times \text{Erms} \]  

where PIV is the maximum peak inverse voltage and Erms is the power transformer RMS secondary voltage. Although Equation (1) is valid only for a sinusoidal waveform (rather than the square wave output of T1), using this equation builds in a margin of safety.

An easier way to estimate the required diode total PIV rating for each leg is to simply equate it to the no-load DC output voltage, which is rated at +800 VDC as per Section II. Since this is far in excess of the 1N2071 600 PIV rating, the Heathkit engineers correctly decided to employ two series diodes in each leg for a total nominal rectifier PIV rating of 1,200 volts.

Although at first glance it might seem that the 1,000 PIV rating of the 1N4007 replacement diodes would eliminate the need for two series diodes, this would be marginal design practice that would leave this margin a little thin for conservative design standards. Thus, even with the higher 1N4007 PIV rating, two series diodes should still be used in each voltage doubler leg.
C. SERIES RECTIFIER DIODE REVERSE VOLTAGE ISSUES

Although I have always given the Heathkit engineers high marks for their circuit designs, I have to offer an (amicable) criticism of their practice of omitting shunt voltage equalizing resistors in their series rectifier diode strings (this topic is discussed in more depth in Section IV-D below). In a paper I recently read on Heathkit upgrades for the SB-200 linear amplifier, this same topic was addressed.

As it happens, the SB-200 employs a similar full-wave voltage doubler circuit that employs the same 1N2071 silicon rectifier diodes. Since the SB-200 requires a +2,400 VDC plate supply, however, eight diodes are employed in each leg to obtain the necessary PIV rating. However, no shunt voltage equalizing resistors are employed.

The author of this paper tactfully addresses this questionable Heathkit design practice as “remarkable”, but then goes on to say that with modern diodes this practice is acceptable. Once again, I have to offer an amicable disagreement.

To get back to the basics on this subject, the salient issue is the silicon rectifier diode back resistance. If we place two 1,000 PIV diodes in series to effectively increase the total PIV rating to 2,000 volts, our implicit assumption is that both diodes have nearly the same back resistance. If this is not the case, there will be “voltage hogging”. To explain, if one of the diodes has (for example) twice the back resistance of the other, then that diode with the higher back resistance will drop 2/3 (rather than ½) of the total reverse voltage. With simple arithmetic, we can see that the total effective PIV rating of these two series diodes would then be only 1,500 rather than 2,000 volts (i.e., with 1,500 reverse volts applied across the series pair, the higher back resistance diode will see its maximum rated 1,000 PIV).

To resolve this matter, we need a better understanding of the characteristics of diode back resistance. Unfortunately, diode back resistance is not directly specified in the 1N4007 diode data sheet. The diode specification most closely related to back resistance is the reverse (leakage) current. The “typical” reverse current for a 1N4007 at its maximum 1,000 volts reverse voltage at 25°C is given as 0.05 microamperes (which corresponds to a 20,000 megohm back resistance).

However, this same data sheet lists the “maximum” reverse current for this same diode as 10 microamperes (which corresponds to a far lower 100 megohm back resistance). This in itself is a huge variation, but it even gets worse. At 100°C, the “typical” and “maximum” numbers are given as 1.0 and 50 microamperes, respectively, corresponding to back resistances of 1,000 megohms and 20 megohms, respectively.

Clearly, diode back resistance is an uncontrolled parameter that is all over the place, varying both from unit to unit and over temperature. Given the above numbers, it seems amazing that Heathkit’s practice of placing these diodes in series without shunt voltage equalizing resistors could ever have worked. Equally clearly, the problem cannot be solved simply by substituting modern diodes since back resistance is still an uncontrolled and unspecified diode characteristic. I have to think that what pulled Heathkit through on this (aside from a generous dose of luck) was that most of the diodes supplied with their kits must have come from the same batch.
D. EQUALIZING SERIES RECTIFIER DIODE REVERSE VOLTAGE

The issues associated with the highly variable back resistances of series diodes have been well-known for many years along with a mature and time-proven solution. Essentially, the remedy is to place shunt “swamping” resistors of the same value across each diode in the series string. If this resistor value is much lower than the diode back resistance, then the effective back resistance is essentially the value of this resistor and the voltage will divide nearly equally across each diode/resistor shunt pair.

Although there is likely no truly “optimum” value for this shunt resistor, the 1974 ARRL Radio Amateur’s Handbook in its chapter on AC operated power supplies provides the following rule-of-thumb:

\[ Rs = PIV \times 500 \]  

where \( Rs \) is the required value of shunt resistance and \( PIV \) is the diode rated peak inverse voltage. Essentially then, the author recommends using 500 ohms of resistance per diode \( PIV \) rating. For a 1N4007 diode rated at 1,000 \( PIV \), the required resistor value would be 500,000 ohms. A 470,000 ohm resistor is thus selected as a good-match standard value.

Again referring to the HP-13 schematic of Figure 1, the 800 volt open-circuit high-voltage is dropped across four rectifier diodes. If 470,000 ohm voltage equalizing resistors are placed across each diode, then the voltage across each 470,000 ohm resistor is 800/4 = 200 volts. The resulting power dissipation in each of these resistors can then be computed by Ohm’s Law as \( E \times E/R = 200 \times 200/470,000 = 0.085 \) watts.

Purely from the standpoint of power dissipation, we could use 1/8 watt 5% carbon film resistors. However, resistors also have maximum voltage ratings and it would be unsafe to use a 1/8 watt resistor for this high-voltage application. 1/4 watt 5% carbon film resistors have a rated maximum working voltage of 250 VDC which would probably be adequate. However, it is better to use ½ watt 5% carbon film resistors with their higher rated maximum working voltage of 350 VDC. The modified diode section of the full-wave voltage doubler is illustrated in Figure 2.

![Figure 2 - Full-Wave Voltage Doubler Modified to Include 1N4007 Silicon Diodes and Shunt Voltage Equalizing Resistors](image)

Figure 4 is a photo showing D1-D4 (all 1N4007s) mounted piggy-back on their associated 470k 1/2W equalizing resistors (located behind C3 and C4).
SECTION V - ELECTROLYTIC CAPACITOR REPLACEMENT

A. OVERVIEW

Electrolytic capacitors (especially high-voltage ones) are likely not to be reliable after 40+ years of service. Although the electrolytic capacitors in my HP-13 were functional, I decided to replace them for this reason.

Of all the HP-13 restoration tasks, replacing the 10 electrolytic capacitors turned out to be the most difficult and time consuming. Although high-voltage electrolytic capacitors are still available, there are no longer any direct fit/form/function replacements for the original 1960s-vintage electrolytic capacitors employed in the HP-13. As a result, adaptations must be made to accommodate the different sizes and footprints of modern electrolytic capacitors.

On the positive side, modern electrolytic capacitors are much smaller, better performing, and more reliable than their 1960s-vintage predecessors. Since electrolytic capacitors have service lives that are much shorter than nearly all other components aside from vacuum tubes and dial lights, I chose premium-grade replacements.

In the following paragraphs, the important characteristics of high-voltage electrolytic capacitors are discussed, followed by identification of specific modern substitutes for the obsolete originals. Suggestions are then made as to how to install these modern substitutes in the HP-13.

B. IMPORTANT CHARACTERISTICS OF ELECTROLYTIC CAPACITORS

1. Capacitance and Voltage Rating - Replacement electrolytic capacitors should have capacitances and voltage ratings equal to or greater than the originals.

2. Service Life - The service life of electrolytic capacitors is typically in the order of thousands of hours, which surprisingly is only somewhat better than that of vacuum receiving tubes. Service life is highly dependent upon operating temperature, applied voltage, and applied ripple current. When operated conservatively, electrolytic capacitors last far longer than when they are operated near their maximum ratings.

3. Temperature Rating - The original electrolytic capacitors employed in the HP-13 (and most non-military electronic equipment built in the 1960s) are rated for operation up to +85°C. Keeping in mind that the service life of electrolytic capacitors is typically in the order of thousands of hours and that this service life degrades at higher temperatures, I recommend that premium grade capacitors rated for operation up to +105°C be used for longest service life.

4. ESR (Equivalent Series Resistance) - Since electrolytic capacitors dissipate a certain percentage of the charge applied to them into heat, they are characterized as having an
equivalent series resistance. This ESR is frequency sensitive, but is mostly constant over the frequency range of interest (under 1,000 Hz) for high-voltage power supplies. Low ESRs are desirable for good performance and long life.

5. AC Ripple Current - Electrolytic capacitors employed as power supply filters are subject to AC ripple current as a consequence of the fact that there is always some AC ripple voltage across them. Since this ripple current flows through the capacitor ESR, heat is generated that shortens capacitor life. It is therefore important that electrolytic capacitors be selected both for high ripple current capacity and low ESR.

C. REPLACEMENTS FOR C3, C4, C8, C9, & C10 (20 uF/450 V)

C3, C4, C8, C9, and C10 are the five 20 uF/450 V electrolytic capacitors mounted in a row at the rear-most section of the HP-13 circuit board (adjacent to the 2 watt resistors). As per the schematic of Figure 1, C3/C4 are used in the high-voltage supply while C8-C10 are used in the low-voltage supply. Since the high-voltage supply imposes the most demanding requirements on these capacitors, we will focus primarily on C3/C4.

A vendor search to locate a 20 uF/450 V replacement electrolytic capacitor was unsuccessful. However, a premium-grade 47 uF/450 V manufactured by Panasonic (P/N EEU-EE2W470) was available from Digi-Key Corp. (P/N 13677-ND). The relevant specifications for this capacitor are as follows:

Temperature Range: -25°C to +105°C
Rated ESR @ 120 Hz: 6.77 ohms
Rated Ripple Current (120 Hz/105°C): 1.2 amperes

The rated service life is dependent upon a number of variables, but was very favorable compared to other capacitors that were also considered.

To determine the suitability of this capacitor for the application at hand, we must first calculate the overall impedance of this capacitor, which comprises the 6.77 ohm ESR in series with the capacitive reactance at the 3,000 Hz ripple frequency (i.e., twice the rated inverter 1,500 Hz switching frequency for the full-wave voltage doubler). First, we compute the capacitive reactance:

\[ X_c = \frac{1}{(2 \times \pi \times F \times C)} \]

\[ = 1.13 \text{ ohms} \] (3)

where \( X_c \) is the capacitive reactance, \( \pi \) is 3.14159, \( F \) is 3,000 Hz, and \( C \) is 47 uF.

Next, the total impedance is found by vectorially adding \( X_c \) and the ESR as follows:

\[ Z = \text{Square Root} \left( X_c \times X_c + \text{ESR} \times \text{ESR} \right) \]

\[ = \text{Square Root} \left( 1.13 \times 1.13 + 6.77 \times 6.77 \right) \]

\[ = 6.86 \text{ ohms} \]
According to the HP-13 specifications, the high-voltage ripple is rated at 1% under a 250 mA (presumably typical) load. Since the high-voltage DC output under a 250 mA load is specified as 750 volts, 1% ripple corresponds to 7.5 volts RMS (based on the commonly-accepted definition of ripple percentage). Given this to be the case, and given that only half of this 7.5 volt RMS ripple voltage (Vr) will appear across each capacitor (since C3/C4 are in series), the approximate ripple current is as follows:

\[ I_r = \frac{V_r}{Z} \]
\[ = \frac{3.75}{6.86} \]
\[ = 0.474 \text{ amperes} \]

where \( I_r \) is the RMS ripple current, \( V_r \) is the RMS ripple voltage, and \( Z \) is the capacitor total impedance as defined in equation (4). Since 0.474 amperes is well below the 1.2 ampere capacitor ripple current rating, we can expect long capacitor service life.

The reason that equation (5) is an approximation is that the ripple voltage has a “sawtooth” rather than sinusoidal characteristic. Since a sawtooth waveform has odd-order harmonics (e.g., at 9,000 Hz, 15,000 Hz, 21,000 Hz, etc.), these harmonics result in additional ripple current since the capacitive reactance \( X_c \) as defined in equation (3) progressively diminishes at these higher frequencies. However, the magnitude of these harmonics also progressively diminishes as they increase in order. To account for the additional ripple current contributed by these harmonics we can add 15% or so to the result of equation (5), but even with this addition the ripple current is still very comfortably within the capacitor 1.2 ampere rating.

Another imperfection associated with the above computations is that the rated 6.77 ohm capacitor ESR is specified for the 100-120 Hz ripple frequency (typically associated with full-wave rectifiers operated from standard 100-120 Hz AC mains), rather than for the inverter 3,000 Hz ripple frequency. It is therefore reasonable to expect that the ESR is different at 3,000 Hz as compared to 120 Hz. Fortunately, capacitor ripple current ratings tend to improve as a function of frequency, so this issue actually works in favor of a margin of safety.

In reality, the above computation overstates ripple current \( I_r \) since the substitution of the larger capacitor (47 uF versus 20 uF) substantially reduces the ripple voltage \( V_r \). As a result, the margin of safety is further improved.

Since ripple voltage \( V_r \) across C8/C9/C10 used in the low-voltage supply is even lower, this same capacitor can be used with an even greater margin of safety.

Figure 3 is a photo of the modern 47 uF/450 V Panasonic replacement capacitor (bottom) along with the original 20 uF/450 V General Instrument Corp. unit (top). This picture is worth a thousand words on the topic of improvements in electrolytic capacitor technology since the 1960s.

In general, there is little or no downside to using replacement filter capacitors with higher capacitance than the originals provided that good quality units are used with adequate ripple current ratings as discussed above. Although larger filter capacitors result in more surge current when the power supply is turned on, modern silicon power diodes (e.g., the 1N4007) have very high surge current ratings. The advantage of higher capacitance
units, of course, is lower ripple voltage.

D. REPLACEMENTS FOR C11a & C11b (20 uF/150 V)

As per the schematic of Figure 1, C11 is a dual electrolytic type (both sections 20 uF/150 V) that is used to filter the rectified bias voltage (-130 VDC nominal maximum). Although the 47 uF/450 V capacitors used for the high- and low-voltage supplies as discussed above are higher rated than necessary for use in this bias supply (both in terms of capacitance and voltage rating), I decided to use them since I had them on hand and they were not very expensive.

E. MOUNTING C3, C4, C8, C9, C10, C11a, & C11b

Although the 47 uF/450 V capacitors selected to replace C3/C4/C8/C9/C10 offer great performance and reliability, they did not fit the HP-13 PC board patterns that were made for these capacitors. While the replacement capacitors are much smaller than the originals, the bigger problem is that they are radial lead units (whereas the originals are axial lead units). Since modern capacitors are designed mostly for PC board mounting, it is increasingly difficult to find axial lead capacitors.
Since these capacitors are small enough to be mounted upright, I mounted them as pictured in Figure 4. Although the capacitor leads were long enough to reach the original component PC board mounting holes, these capacitors were not well-secured to the board using this unorthodox mounting technique.

To correct this issue, I staked these capacitors down to the board using RTV (RTV is a form of silicone sealant). I used Permatex Part 66B (which is non-corrosive and available in many hardware and auto supply stores), but many other types are equally suitable. After allowing several hours to cure, the RTV secured these capacitors firmly to the PC board.

F. REPLACEMENTS FOR C1 & C12 (10 uF/25 V)

As per the schematic of Figure 1, C1 and C12 (both 10 uF/25 V) are the inverter timing capacitors that are used to establish the 1,500 Hz (nominal) switching frequency. Although it was not clear to me what the ripple current requirements were for these capacitors, I decided to once again go with premium-grade replacements.

I selected 10 uF/63 V capacitors manufactured by Panasonic (P/N EEU-EB1J100) and available from Digi-Key Corp. (P/N P13138-ND). As expected, these capacitors are much smaller than the original units. C1 is shown in Figure 5 (just below 270 ohm resistor R1). I staked-down both C1 and C12 with RTV.

Although the nominal inverter switching frequency is 1,500 Hz, the actual measured switching frequency with the original C1/C12 capacitors was near 1,600 Hz. This frequency rose slightly to near 1,700 Hz with the replacement capacitors.

G. REPLACEMENT FOR C6 (100 uF/50 V)

Referring to the schematic of Figure 1, C6 is a large bypass capacitor intended to hold the T1 inverter transformer center tap at AC ground. In conjunction with choke L2, it also serves to help filter inverter switching spikes from the +12 VDC input.

Since there was no question in my mind that C6 needed to be a high-quality capacitor, I selected a premium-grade 220 uF/50 V unit manufactured by Panasonic (P/N EEU-EB1H221) and available from Digi-Key Corp. (P/N P13131-ND). To my surprise, however, this capacitor became very warm to the touch when the power supply was powered-up. Probing this replacement capacitor with an oscilloscope, the voltage across it appeared as in Figure 6 (no load on power supply).
As per this photo, the magnitude of the switching spikes is 3 VPP, which is very large for a +12 VDC input. Clearly, the large ripple current resulting from these spikes was responsible for the capacitor overheating.

To improve things, two additional 220 uF/50 V capacitors were added in parallel with C6 (for a total of 660 uF). The result of this additional capacitance is shown in Figure 7.

As per this photo, including the additional 440 uF of capacitance cut the switching spike magnitude in half to approximately 1.5 VPP. Also, the additional capacitance eliminated the heating problem as a result of the fact that this additional capacitance reduced ripple voltage and distributed the lesser resulting ripple current through three (rather than one) capacitors.
Although this was a significant improvement, it seemed that this ripple magnitude was still high (especially considering the fact that there was no load on the power supply). Also, it seemed that further improvement would require a large amount of additional capacitance. My next step then was to add eight 470 uF/25 V capacitors in parallel with the three 220 uF/50 V units already in place. With this very large amount of capacitance, the ripple voltage significantly diminished as illustrated in Figure 8.

These additional 470 uF/25 V capacitors were used since they were already in stock. These units are manufactured by Panasonic (P/N ECA-1EHG471) and are available from Digi-Key Corp. (P/N P5543-ND). These capacitors are visible in Figure 4. (Note that the 470 uF/25 V capacitors are grouped into sets of four and bundled together using heat-shrink tubing.)

With the benefit of hindsight, however, it is clear that this piecemeal and incremental approach leaves much to be desired. Subsequent to the photo shoot for Figure 4, these capacitors were all removed and replaced by a single 4,700 uF/35V electrolytic capacitor suitable for this application. This capacitor is manufactured by Panasonic (P/N ECA1VHG472) and available from Digi-Key Corp. (P/N P5558-ND). This unit has a very high ripple current rating (1.91 amperes).

In closing, the original 100 uF/50 V capacitor used for C6 appears to have been very marginal for the intended application. 100 uF is far too small to provide good ripple filtering, and it is almost certain that this capacitor was being operated far in excess of its ripple current rating.

Also, even though Heathkit chose a 50 V capacitor, in most mobile +12 VDC applications it is safe to use 25 V capacitors. This is especially the case if a power Zener diode is employed as an over-voltage clamp. This useful input power protection technique is discussed in detail in Section VI.
H. RESISTORS

Although a discussion of the HP-13 resistors might seem outside the purview of this discussion of its electrolytic capacitors, replacing the capacitors also presents an opportunity to check these resistors. More specifically, significant disassembly of the HP-13 is required to replace its capacitors. As a result, most of the resistors will have at least one lead disconnected during this process so it is easy to check their values with an ohmmeter.

Although resistors are not usually considered as high-maintenance components prone to failure, the resistors used in the HP-13 are all power resistors and have thus been subjected to thermal stress. Also, these resistors are all carbon composition types, which are significantly less stable in value than the more modern carbon film types.

The resistors in my HP-13 all measured on the high side of their nominal values, in some cases having drifted outside the 10% tolerance specification. However, the values had not changed enough to warrant replacing any of them.

The high-voltage supply bleeder resistors (R3/R4; 100k/2W) are the most critical. Although a modest upward change in their values is of no great concern, it is important that their values track with each other reasonably well.

To explain, if the value of R3 is significantly different than the value of R4, there will be an unequal voltage division across C3 and C4 (“voltage hogging”). As a result, voltage appearing across one of these two capacitors might come close to or exceed its 500 V rating. Fortunately, these resistor values were closely matched in my HP-13.

Any resistor that is excessively out of tolerance (i.e., by more than 20% of its nominal value) should be replaced. Similarly, resistors that appear burned or “cooked” should also be replaced. On the positive side, resistors employed in extensively used 40+ year old equipment are fully aged and will likely not drift in value much further.
SECTION VI - OVER-VOLTAGE & REVERSE POLARITY PROTECTION ZENER

An apparent HP-13 design shortcoming is that it has neither over-voltage nor reverse-polarity protection at its 12 VDC input. This was remedied by adding a single Zener protection diode.

The operation of this protection diode can best be explained by examining an actual circuit where it has been successfully employed. Figure 9 is a simplified schematic of the input power circuitry of the RDF Products DFP-1000A DF bearing processor (the predecessor to the current DFP-1000B). The following detailed explanation of this circuit is an excerpt (with some minor paraphrasing) from the DFP-1000A Service manual:

“The DFP-1000A contains robust power input protection circuitry to protect the unit from the inadvertent application of reverse-polarity DC input power and input voltages substantially exceeding the maximum +16 volt DC input voltage rating. The essential elements of this circuitry are illustrated in Figure 9.

Referring to Figure 9, 11-16 VDC input power is applied from the external power source to the DFP-1000A rear-panel power connector. This DC power is then applied through the 2.5 ampere rear-panel fuse and then to the front-panel ON/OFF switch.

The shunt 18-volt power Zener diode (D9, located on the Front-Panel Board) works in conjunction with the fuse to provide both reverse-polarity and over-voltage protection. If reverse-polarity power is applied, D9 forward-biases and clamps the input voltage at approximately -1 VDC. The resulting high input current almost immediately blows the fuse and thus protects the subsequent circuitry.

If over-voltage is applied (if the DFP-1000A is inadvertently powered from a +28 VDC aircraft power source, for example), D9 clamps the input voltage at +18 VDC. Once again, the resulting high input current almost immediately blows the fuse and thus protects the subsequent circuitry.

Although D9 is a heavy-duty power Zener diode capable of dissipating up to 5 watts, its ability to survive reverse-polarity and over-voltage power inputs depends upon the circumstances. It has been our experience that D9 is sufficiently robust to survive the application of reverse-polarity power. (The large inrush of current blows the 2.5 ampere fuse before the junction temperature of D9 rises to the point where the diode junction fuses, although it is possible that this might not be the case if the current capacity of the power source is sufficiently high.) If D9 survives (as is usually the case), it is necessary to replace only the 2.5 ampere fuse.
In cases where over-voltage is applied, however, it has been our experience that D9's junction typically fuses before the 2.5 ampere fuse blows (although it is possible that D9 can survive if the external power source has a sufficiently low current-limiting threshold), resulting in both a blown fuse and D9 presenting a direct short circuit as a result of its fused junction. In this case, it is necessary to replace both the 2.5 ampere fuse and D9. Even so, the input power protection circuitry has still functioned effectively, preventing major DFP-1000A damage at the expense of requiring replacement of only two inexpensive components.”

Since the HP-13 12 VDC input circuitry is protected by a 30 ampere circuit breaker rather than the faster acting 2.5 ampere fuse employed in the DFP-1000A, it is probable that the 1N5355B Zener diode would not survive the application of reverse-polarity power. Even so, this inexpensive and readily replaceable part would still protect the HP-13 power transformer and power transistors (parts that would likely be irreplaceable or very hard to find at best).

An incidental benefit of this power protection Zener is that it limits input voltage spikes to 18 volts. As a result, the voltage rating of C6 need be no greater than 25 V for safe operation. (The 4,700 uF capacitor substituted for C6 as discussed above is rated at 35 V only because this 35 V capacitor has a higher ripple current rating than the comparable 25 V unit.)

I strongly recommend adding this inexpensive part to the HP-13. Referring to the HP-13 schematic of Figure 1, the 1N5355B cathode be connected to the positive terminal of C6 (i.e., at the power transformer center tap) and the anode should be connected to ground.

A possible amendment to this technique would be to select a similar power Zener with a lower forward voltage rating. In the case of the DFP-1000A/B discussed above, the maximum specified input voltage is 16 VDC. Since the forward voltage tolerance for this Zener family is +/-5%, we decided to use the 18 volt 1N5355B to be absolutely certain that there would be no unwanted Zener forward conduction at the maximum specified 16 VDC input. Also, we validated this choice by confirming that the DFP-1000A/B would not suffer damage from prolonged exposure to an 18 VDC input.

In the case of the HP-13, however, the maximum rated input voltage is only 14.5 VDC so it would be reasonable to substitute a Zener with a lower forward voltage rating. The 16 volt 1N5353B would be a good candidate, and possibly even the 15 volt 1N5352B.

The downside of using a Zener with too low a forward voltage rating is that it can conduct and gulp large amounts of current at too low an input voltage. As a case in point, if the 15 volt 1N5352B is selected for the HP-13, a Zener at the bottom edge of the rated +/-5% tolerance would begin conducting at 14.25 VDC (which would unfortunately be inside the HP-13 14.5 VDC maximum rated input voltage specification).

Ultimately, this is a matter of deciding how far we want to go to protect the HP-13. As discussed in Section VII, the germanium switching transistors (Q1 & Q2) would likely be very difficult to replace. Given this reality, the prudent decision might well be to use a lower voltage Zener, particularly if the applied DC voltage is not likely to rise too close to the HP-13 14.5 VDC maximum rated input.

To further amplify on this, a typical lead-acid battery can reach a 14.5 terminal voltage under hard charging although lower terminal voltages are more typical. If we really wanted to finesse this, we could buy a small quantity of nominal 14 volt (1N5351B) and 15 volt
(1N5352B) Zeners and then select them by careful measurement to find one with forward voltage threshold very close to 14.5 volts.

1N5355B Zener diodes are available from many sources including Digi-Key Corp. (P/N 1N5355BRLGOSCT-ND). This part is also available from Mouser Electronics (P/N 610-CZ5355B). The 1N5351B and 1N5352B are also available from these same sources.
SECTION VII - SWITCHING TRANSISTORS (Q1 & Q2)

It would seem reasonable to want to replace the two power switching transistors in a 40+ year old inverter power supply. Unfortunately, I found this task to be far from straightforward and ultimately decided to leave the originals in service.

As per the schematic of Figure 1, Q1 and Q2 are identical PNP power switching transistors used in conjunction with T1 and various peripheral components to form a 1,500 Hz power oscillator. Although the circuitry is conventional and straightforward, the HP-13 assembly manual does not identify these transistors other than by the Heathkit house part number (417-60). An examination of the transistors themselves revealed only this same house part number, Motorola’s logo and the additional identifier “SP838-1”. None of my Motorola data manuals (even the very old ones dating back to the 1970s) list the SP838.

Based on an internet search of various Heathkit users’ groups, this transistor appears to be a 45 volt 25 ampere 100 watt PNP germanium type that has been out of production for many years. This is not surprising given that germanium transistors, as far as I know, are no longer manufactured and have long been supplanted by more reliable and temperature-stable silicon types.

One of the postings I found suggested the NTE179 and the ECG197 as generic replacements (although the poster stated that he had not actually tried them). Also, these transistors are very expensive, which is likely an indication that they are no longer in production and that the remaining stocks are nearly depleted.

Another posting claimed success using a 2N6330 silicon transistor, although it reported occasional inverter mis-starts where the inverter would not oscillate at power-up. (The reported remedy was to switch the HP-13 off and then back on again.) This issue suggests that it may be necessary to use a matched transistor pair for the HP-13 to start reliably. Unfortunately, the 2N6330 is not available from my primary semiconductor suppliers (Mouser Electronics and Digi-Key Corp.) and is likely an obsolete or hard-to-find part.

I ultimately decided just to leave the original transistors in place since they appeared to work properly. My primary concern was that attempting a substitution might risk damaging the power transformer (which would force me to scrap the whole power supply since it would be very difficult to find a replacement transformer from any source other than another HP-13).

Even so, I see no reason why the two germanium transistors could not be replaced with modern silicon types. This task would, of course, have to be done carefully and with the full expectation that some circuit redesign might be necessary. Such an effort would be a worthy follow-on project.
SECTION VIII - PARTS VENDORS

As discussed above, I purchased the necessary parts from Digi-Key Corp. since they have an excellent selection of capacitors. Other parts vendors with good parts selections and reasonable minimum order requirements are Jameco Electronics and Mouser Electronics. Contact information is as follows:

Digi-Key Corp. - www.digikey.com
Jameco Electronics - www.jameco.com
Mouser Electronics - www.mouser.com

Post Note:

I received a message from reader Burkhard Riemer in Germany who has also reconditioned an HP-13. Burkhard advises that a European source for capacitors and other components can be found at the following link:

http://www.die-wuestens.de/dindex.htm?/katalog.htm